300	FREQUENCY SHIFT KEYING OR MINIMUM SHIFT KEYING DEMODULATOR	324	Input signal applied directly to local oscillator
301	.Including discrete semiconductor device	325	Including phase or frequency locked loop
302	.Input signal combined with local oscillator or carrier	326	Including discrete semiconductor device
303	frequency signal .Including logic element (e.g.,	327	.Input signal split into plural signals
	logic gate or flip-flop	328	Including piezoelectric resonant element
304	PHASE SHIFT KEYING OR QUADRATURE	329	Using a transformer to split
305	AMPLITUDE DEMODULATOR .Including discrete semiconductor	323	input signal
	device	330	Signals taken from primary and secondary windings
306	.Input signal combined with local oscillator or carrier	331	Including plural detector
	frequency signal		diodes (e.g., ratio detector
307	Including phase or frequency locked loop	332	type)Signals taken from plural
308	With parallel signal combiners	222	secondary windings
	(e.g., Costas loop)	333	Including plural detector diodes (e.g., ratio detector
309	Including logic element		type)
	(e.g., logic gate or flip-	334	Including resonant circuits
310	<pre>flop) .Including logic element (e.g.,</pre>	331	tuned above and below input
310	logic gate or flip-flop)		signal carrier frequency
311	PULSE OR INTERRUPTED CONTINUOUS	335	Including plural detector
	WAVE DEMODULATOR		<pre>diodes (e.g., ratio detector type)</pre>
312	Pulse width demodulator	336	Input signal combined with
313	.Pulse position, frequency, phase or spacing demodulator		phase shifted or delayed portion of input signal
314	Including discrete	337	Including LC resonant phase
245	semiconductor device	337	shift circuit
315	FREQUENCY MODULATION DEMODULATOR	338	Input signal split by LC
316 317	.Plural demodulationIncluding amplitude		resonant circuit
317	demodulation	339	Including LC resonant circuits tuned above and below input
318	.Having specific distortion,		signal carrier frequency
	noise or other interference prevention, reduction or	340	Including plural detector diodes (e.g., ratio detector
210	compensation		type)
319	Using feedback to reduce	341	.Input signal converted to and
	distortion, noise or other interference		processed in pulse form (e.g., pulse counter or digital type
320	By cancelling distortion, noise		demodulator)
321	or other interference	342	Including discrete
321	Using amplitude limiting within the demodulator		semiconductor device
322	.Including microwave or	343	Including digital logic
522	distributed parameter		circuitry
	structure	344	.Including signal passed through
323	.Input signal combined with local		single demodulating path
	oscillator or carrier	2.4.5	including resonant circuit
	frequency signal	345	PHASE MODULATION DEMODULATOR

346	.Input signal combined with local oscillator or carrier	370	.Including diode demodulator device
	frequency signal	371	.Coherer type demodulator
347	AMPLITUDE MODULATION DEMODULATOR	372	MISCELLANEOUS
348	.Having plural demodulation outputs		
349	.Having specific distortion,		
	noise or other interference	FORETC	N ART COLLECTIONS
	prevention, reduction or	TORELG	M ANT COMMETTONS
	compensation	EOD OO	0 CLASS-RELATED FOREIGN DOCUMENTS
350	Automatic amplitude	FOR UU	O CLASS-RELATED FOREIGN DOCUMENTS
	stabilization or control		
351	Nonlinearity reduction or		
	compensation		
352	Temperature compensation		
353	Noise reduction or compensation		
354	.Including microwave or		
	distributed parameter structure		
355	With electron discharge device		
356	.Suppressed carrier double		
	sideband type		
357	.Single or vestigial sideband type		
358	.Input signal combined with local		
	oscillator or carrier		
	frequency signal (e.g.,		
	synchronous demodulator)		
359	Input signal applied directly		
	to local oscillator		
360	Including phase or frequency		
	locked loop		
361	Including sampling, gating, or		
	switching		
362	With three or more terminal		
	discrete semiconductor device		
363	.Input signal split into plural		
	signals		
364	Including three or more		
	terminal discrete		
265	semiconductor device		
365	Including diode demodulator		
266	device		
366	Plural diodes		
367	.Including regenerative feedback in non-oscillating demodulator		
368	.Electron discharge demodulator		
	device having more than two		
	electrodes (e.g., triode,		
	tetrode etc.)		
369	.Including three or more terminal		
	discrete semiconductor		
	demodulator device		